



PJU45N06A / PJD45N06A

60V N-Channel Enhancement Mode MOSFET

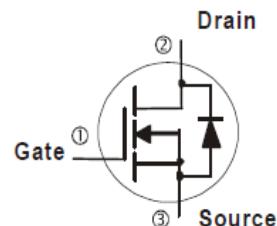
Voltage 60 V Current 45 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V, I_D@30A < 12m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V, I_D@15A < 15m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : TO-251AB , TO-252 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AB Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252 Approx. Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current $T_C=25^\circ C$	I_D	45	A
$T_C=100^\circ C$	I_D	29	
Pulsed Drain Current	I_{DM}	180	
Power Dissipation $T_C=25^\circ C$	P_D	63	W
$T_C=100^\circ C$	P_D	25	
Continuous Drain Current $T_A=25^\circ C$	I_D	9.5	A
$T_A=70^\circ C$	I_D	7.6	
Power Dissipation	P_D	2.5	W
Power Dissipation	P_D	1.6	
Single Pulse Avalanche Energy ^(Note 1)	E_{AS}	61	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal resistance Junction to Case	$R_{\theta JC}$	2.0	$^\circ C/W$
Junction to Ambient	$R_{\theta JA}$	50	

• Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.7	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=30A$	-	10.5	12	$m\Omega$
		$V_{GS}=4.5V, I_D=15A$	-	12	15	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$	-	0.01	1.0	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	± 10	± 100	nA
Dynamic <small>(Note 5)</small>						
Total Gate Charge	Q_g	$V_{DS}=30V, I_D=10A,$ $V_{GS}=10V$ <small>(Note 2,3)</small>	-	39	-	nC
Gate-Source Charge	Q_{gs}		-	6.1	-	
Gate-Drain Charge	Q_{gd}		-	6.7	-	
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0MHz$	-	2256	-	pF
Output Capacitance	C_{oss}		-	145	-	
Reverse Transfer Capacitance	C_{rss}		-	93	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=15V, I_D=10A,$ $V_{GS}=10V, R_G=6\Omega$ <small>(Note 2,3)</small>	-	7.5	-	ns
Turn-On Rise Time	t_r		-	36	-	
Turn-Off Delay Time	$t_{d(off)}$		-	49	-	
Turn-Off Fall Time	t_f		-	12	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	45	A
Diode Forward Voltage	V_{SD}	$I_S=1A, V_{GS}=0V$	-	0.67	1.0	V

NOTES :

1. The test by surface mounted on 1 inch FR4 board with 2oz copper.
2. $L=0.1mH, I_{AS}=35A, V_{DD}=25V, V_{GS}=10V, R_G=25ohm$, Starting $T_J=25^\circ C$
3. The Power dissipation is limit by $150^\circ C$ junction temperature.
4. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
5. Guaranteed by design, not subject to production testing



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TYPICAL CHARACTERISTIC CURVES

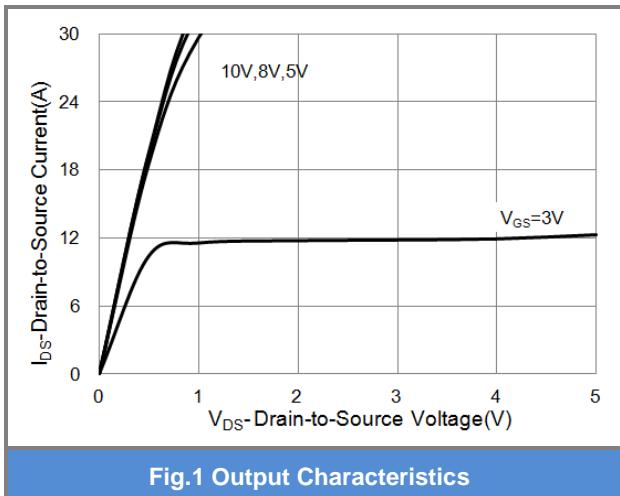


Fig.1 Output Characteristics

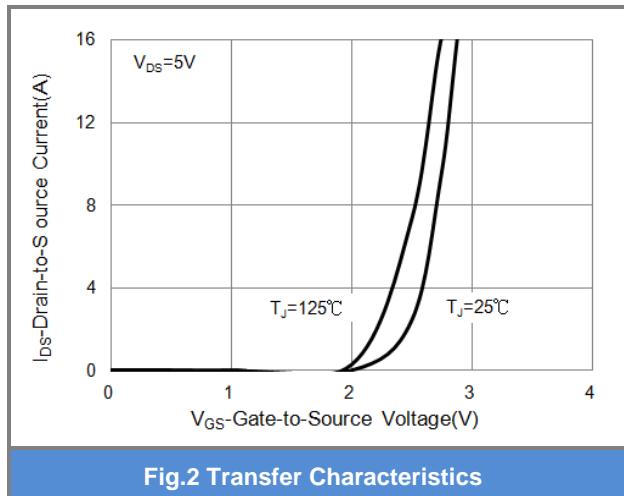


Fig.2 Transfer Characteristics

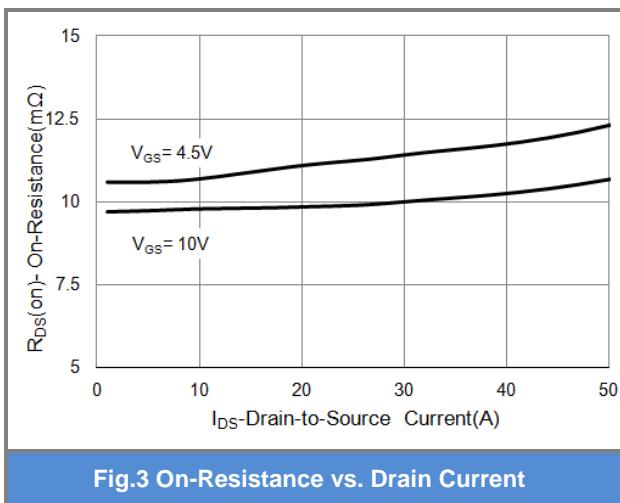


Fig.3 On-Resistance vs. Drain Current

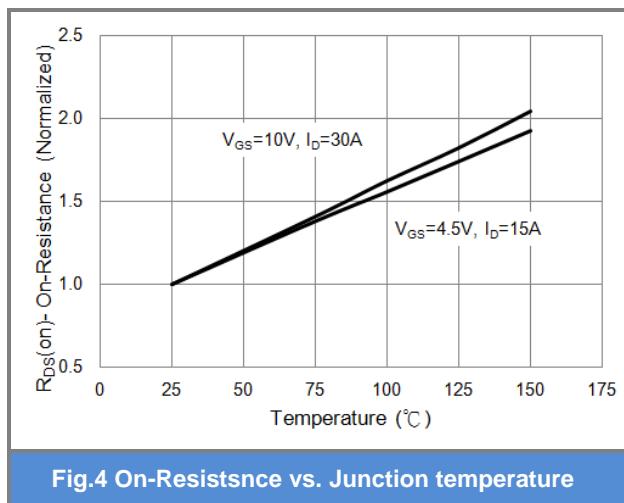


Fig.4 On-Resistance vs. Junction temperature

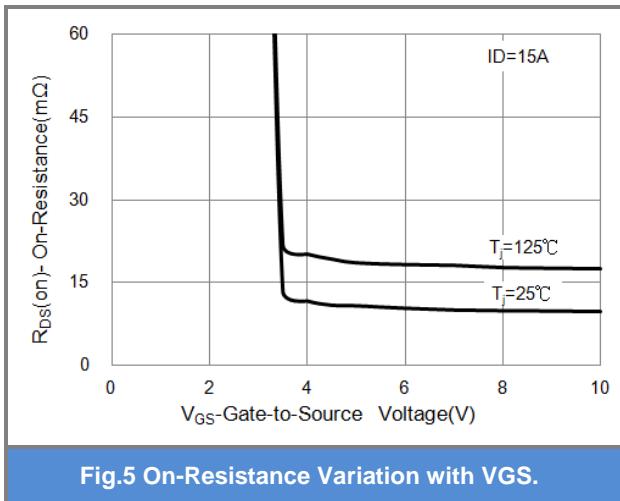


Fig.5 On-Resistance Variation with VGS.

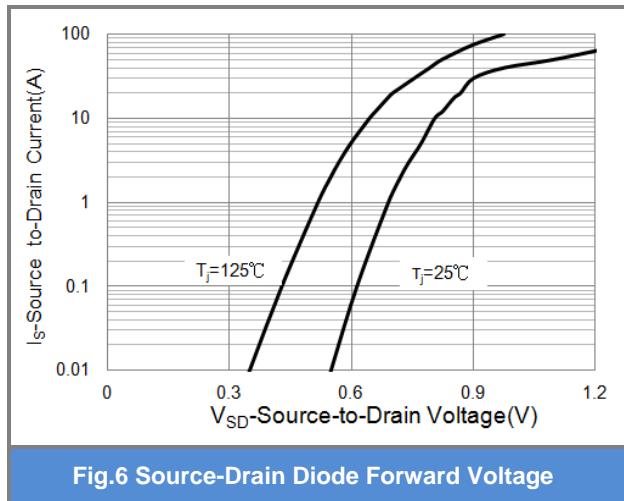
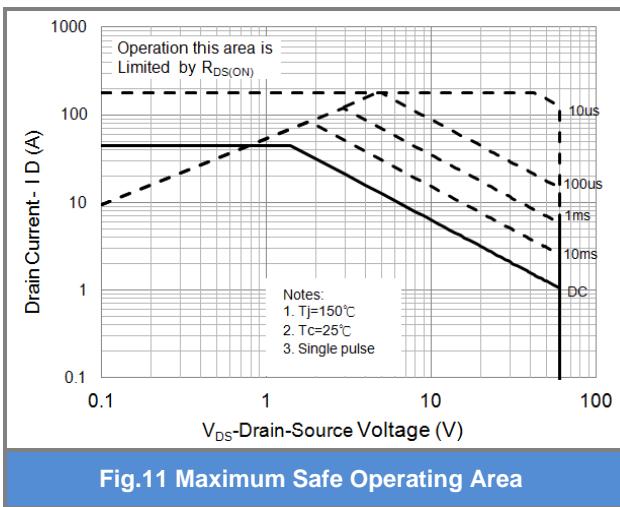
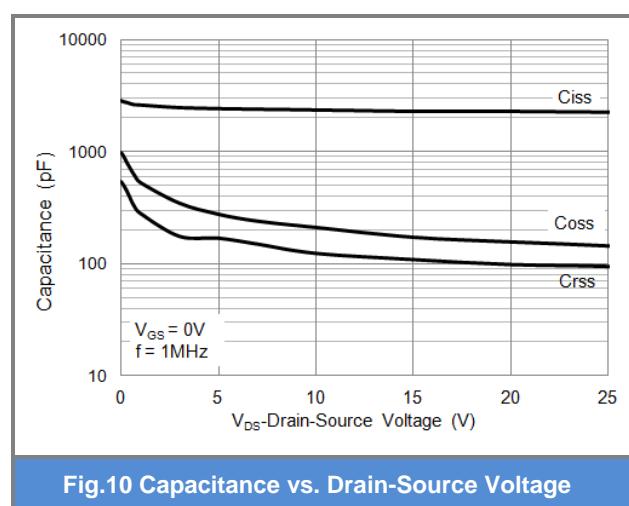
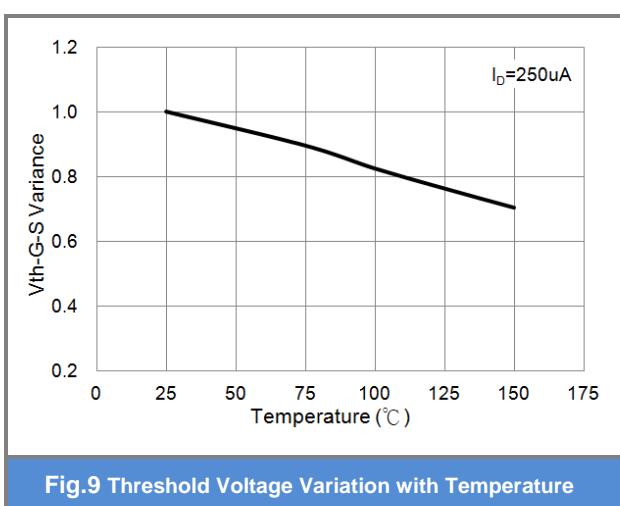
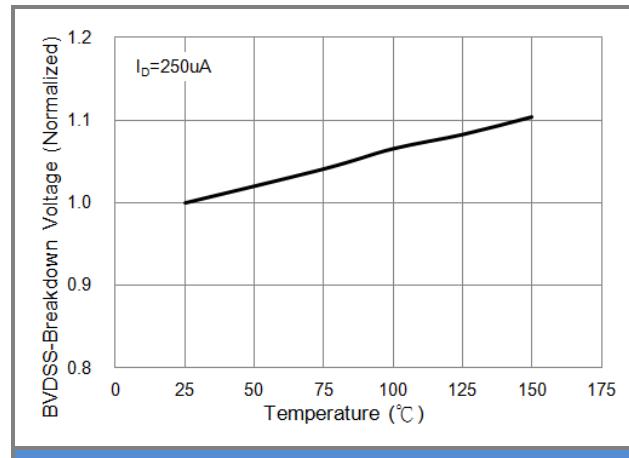
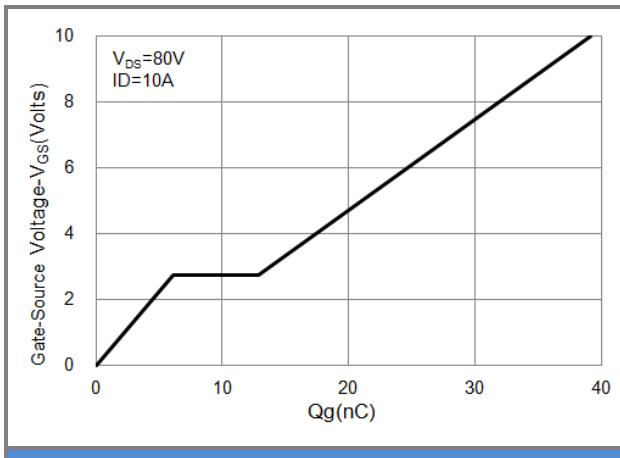


Fig.6 Source-Drain Diode Forward Voltage



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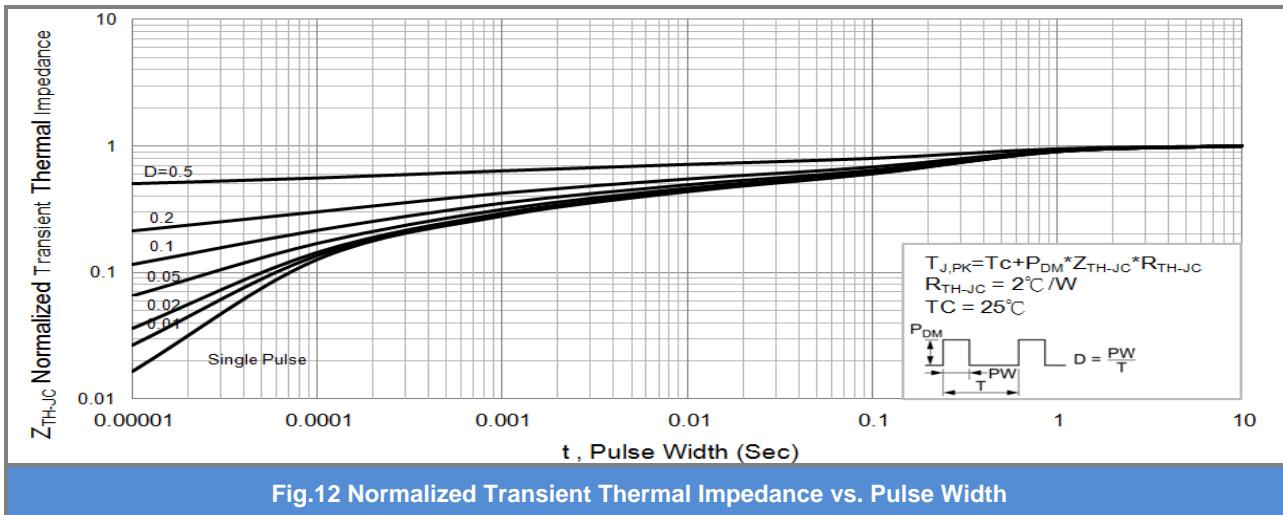


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width



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Packaging Information

TO-252 Dimension	Unit: mm	TO-251AB Dimension	Unit: mm

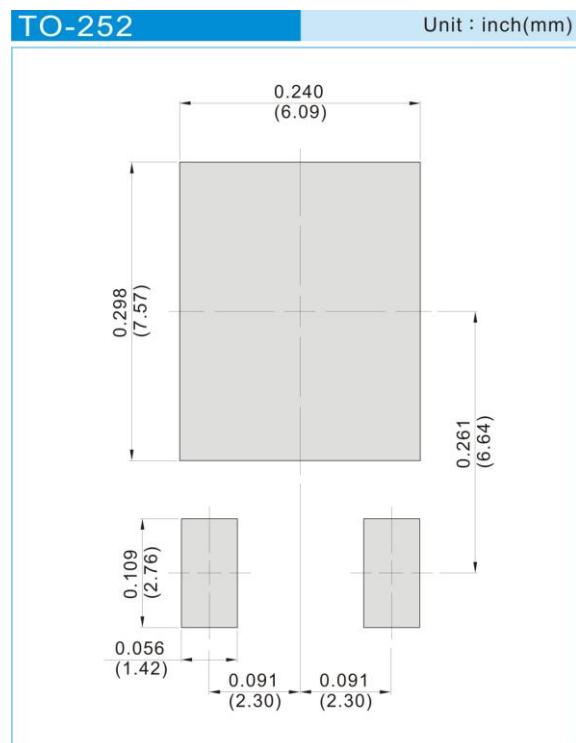


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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD45N06A_L2_00001	TO-252	3,000pcs / 13" reel	D45N06A	Halogen free
PJU45N06A_T0_00001	TO-251AB	80pcs / Tube	U45N06A	Halogen free

MOUNTING PAD LAYOUT





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